ASML-5829 Schottky Assisted Low Power PIN Diode Limiter

Data Sheet



Description

The ASML-5829 is specifically designed for low power limiter applications, where it can be used to protect the receiver system from being damaged by large input signals, and allow the receiver system to function normally with the absence of large signal. The Schottky enhanced limiter will have a lower limiting threshold compared to the more conventional self-biased PIN limiter. The PIN diode is placed at the input, to protect the Schottky from high RF power levels.

Pin Connections, Package Marking & Orientation, SOT-323



Notes: GB = Device Code ? = Month code indicates the month of manufacture

Features

- Low Power Limiter with unique combination of PIN and Schottky Diode
- Low limiting threshold power (OP1dB: 6.05 dBm @900MHz)
- Semi integrated solution in Surface Mount SOT-323 Package
 - increase flexibility
 - save board space
 - reduce cost
- PIN Diode features:
 - Low Capacitance
 - Low Resistance at Low Current
 - Low Failure in Time (FIT) Rate^[1]
- Schottky Diode features:
 - Low Turn-On Voltage (As Low as 0.34 V at 1 mA)
 - Low FIT (Failure in Time) Rate^[1]

Note:

1. For more information see the Surface Mount PIN Reliability Data Sheet.

Table 1. Absolute Maximum Rating ^[1] $Tc = +25^{\circ}C$, PIN diode

Symbol	Parameter	Units	Absolute Max. for PIN Diode	Absolute Max. for Schottky Diode
IF	Forward Current (1µs Pulse)	Amp	1	1
P _{IV}	Peak Inverse Voltage	V	100	15
Τj	Junction Temperature	°C	150	
T _{STG}	Storage Temperature	°C	-65 to 150	
OJ	Thermal Resistance ^[2]	°C/W	150	

Notes:

1. Operation in excess of anyone of these conditions may result in permanent damage to the device.

2. $T_C = 25^{\circ}C$, T_C where is defined to be the temperature at the package pins where contacts is made to the circuit board.

Table 2. Electrical Specifications, $Tc = +25^{\circ}C$, PIN diode

Parameter and Test Condition	Units	Min.	Тур	Max.
Breakdown Voltage @ $I_R \le 10\mu A$	V	100	128	-
Forward Voltage @ I _F = 30mA	V	-	0.90	-
Typical Series Resistance @ Freq = $100MHz \& I_F = 1mA$	Ohm	-	4.00	-
Typical Series Resistance @ Freq = 100MHz & I _F = 5mA	Ohm	-	1.90	2.5
Typical Total Capacitance @ Freq = 1 MHz & V _R = 5 V	pF	-	0.28	0.375
Carrier Lifetime @ $I_F = 10 \text{ mA} \& I_R = 6 \text{ mA}$	ns	-	200	-
	$\label{eq:Breakdown Voltage @ I_R \le 10 \mu A} \\ Forward Voltage @ I_F = 30 mA \\ Typical Series Resistance @ Freq = 100 MHz & I_F = 1 mA \\ Typical Series Resistance @ Freq = 100 MHz & I_F = 5 mA \\ Typical Total Capacitance @ Freq = 1 MHz & V_R = 5 V \\ \end{array}$	$\begin{tabular}{lllllllllllllllllllllllllllllllllll$	$\begin{tabular}{ c c c c } \hline Breakdown Voltage @ I_R \le 10 \mu A & V & 100 \\ \hline Forward Voltage @ I_F = 30 m A & V & - \\ \hline Typical Series Resistance @ Freq = 100 MHz & I_F = 1 m A & Ohm & - \\ \hline Typical Series Resistance @ Freq = 100 MHz & I_F = 5 m A & Ohm & - \\ \hline Typical Series Resistance @ Freq = 100 MHz & V_R = 5 V & pF & - \\ \hline \end{array}$	Breakdown Voltage @ $I_R \le 10\mu$ AV100128Forward Voltage @ $I_F = 30m$ AV-0.90Typical Series Resistance @ Freq = 100MHz & $I_F = 1m$ AOhm-4.00Typical Series Resistance @ Freq = 100MHz & $I_F = 5m$ AOhm-1.90Typical Total Capacitance @ Freq = 1MHz & $V_R = 5V$ pF-0.28

Table 3. Electrical Specifications, $Tc = +25^{\circ}C$, Schottky diode

mbol	Parameter and Test Condition	Units	Min.	Тур	Max.
R	Breakdown Voltage @ $I_R \le 100 \mu A$	V	15	22	-
	Reverse Leakage Current @ V _{BR} = 1V	nA	-	40	100
	Forward Voltage @ $I_F = 1 \text{ mA}$	V	-	0.32	0.34
	Forward Voltage @ I _F = 10mA	V	-	0.45	0.50
	Typical Total Capacitance @ Freq = $1 MHz \& V_R = 0V$	pF	-	0.7	1.0
)	Typical Dynamic Resistance, I _F = 5mA	Ohm	-	12	-
)		Ohm	-	12	





Figure 1. S11 & S21 vs Frequency at Input Power = 0dBm



Figure 3. Pout fundamental & Pout second harmonic vs Pin at freq = 450MHz



Figure 5. Pout fundamental & Pout second harmonic vs Pin at freq = 1.8GHz



Figure 2. S11 & S21 vs Frequency at Input Power = -30dBm



Figure 4. Pout fundamental & Pout second harmonic vs Pin at freq = 900MHz



Figure 6. Pout fundamental & Pout second harmonic vs Pin at freq = 2.0GHz



Figure 7. Pout fundamental & Pout second harmonic vs Pin at freq = 2.5GHz



Figure 8. Pout fundamental & Pout second harmonic vs Pin at freq = 2.7GHz









Notes: XXX-package marking Drawings are not to scale

	DIMENSIONS (mm)		
SYMBOL	MIN.	MAX.	
Α	0.80	1.00	
A1	0.00	0.10	
В	0.15	0.40	
C	0.10	0.20	
D	1.80	2.25	
E1	1.10	1.40	
е	0.65 typical		
e1	1.30 typical		
E	1.80	2.40	
L	0.425 typical		

Part Number Ordering Information

Part Number	No. of Devices	Container
ASML-5829-BLK	100	Bulk, per Antistatic bag
ASML-5829-TR1	3000	Tape & Reel, per 7" Reel
ASML-5829-TR2	10000	Tape & Reel, per 13" Reel

Tape and Reeling conforms to Electronic Industries RS-481, "Taping of Surface Mounted Components for Automated Placement". For lead-free option, the part number will have the character "G" at the end, eg. –TR2G for a 10K pc lead-free reel.

Recommended PCB Pad Layout for AVAGO's SOT-323 Products



Dimensions in inches

Device Orientation





Note: "AB" represents package marking code. "C" represents date code.

Tape Dimensions and Product Orientation



For product information and a complete list of distributors, please go to our web site: www.avagotech.com

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